Analog Switch Guide



The TI signal switch product portfolio consists of high-performance, low-power digital, analog and specialty switches.

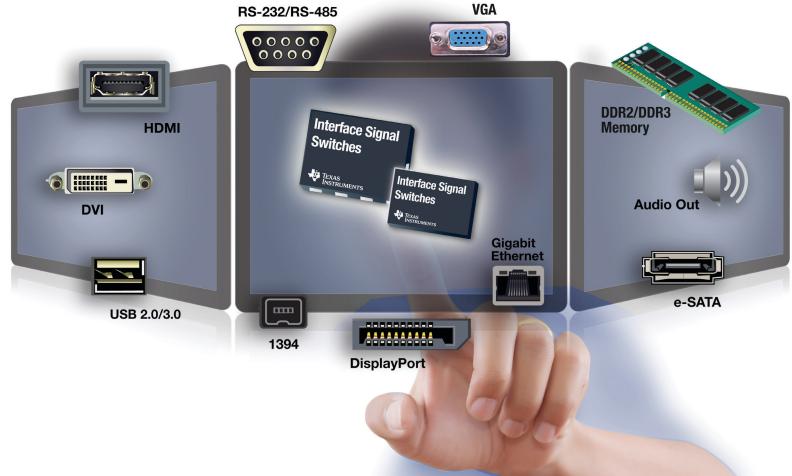


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Today's competitive environment creates a constant need for higher performance. One common method to optimize system performance involves the use of FET switches (also referred to as signal switches) to provide a high-speed bidirectional bus interface between DSPs, CPUs, industry standard buses, memory and peripherals. The Texas Instruments (TI) signal switch product portfolio consists of digital switches, analog switches and specialty switches that provide high-performance, low-power replacements for standard bus-interface devices when signal buffering (current drive) is not required. Availability in advanced packaging (BGA, QFN and WCSP) also allows TI signal switches to occupy reduced board area in space-constrained applications. TI signal switches optimize next-generation datacom, networking, computing, portable communications and consumer electronic designs by supporting both digital and analog applications.

Analog Switches

TI's analog switches are designed to pass (or isolate) analog signals (both voltage and current) and support

Switch Nomenclature

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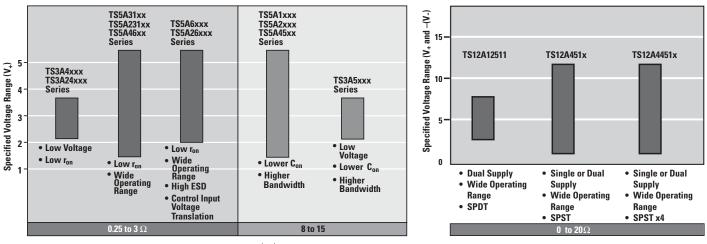
analog applications such as audio and video data transmission. TI analog switches are available in a wide range of voltages (from 0.8 to 12 V), support fast data throughput (up to 2-GHz bandwidth) and offer low on-resistance and input capacitance for decreased signal distortion and insertion loss. TI analog switches are available in the TI Switch (TS) technology family. The TS product family encompasses a variety of analog switches with different ON resistances, bandwidth, charge injection, and total harmonic distortion to target any application.

TS-Series Analog and Speciality Switch Part Numbers TS 3 V 330 R G Y R Prefix: TS = TI Signal switch, TSU = TI Smart switch Image: Comparison of the temperature of te

Analog Switch Overview

Selecting the Right TI Analog Switch

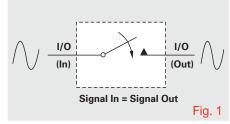
Analog Switch Family



ON-State Resistance Range (ron)

When switches are first considered, a schematic of the ideal switch (similar to the one below) might come to mind. In figure 1, an input signal applied to the left I/O pin (or port) results in an identical output signal at the right I/O pin, and vice versa. However, in the real world, switches are not ideal; and there is always some loss. In the case of clean, properly working mechanical switches, the loss is so miniscule that it hardly bears noting.

Ideal Switch



Like mechanical switches, solid-state switches are not ideal either. In fact, losses associated with solid-state switches can be significant. Why use a switch like this if it is so far from ideal? The answer is convenience and reliability. Mechanical switches are subject to wear out and mechanical reliability issues. Solid-state switches are small, fast, easy-to-use and easy-to-control and consume relatively little power compared to traditional electrically controlled switches such as relays. The switches referred to here are Complementary Metal-Oxide Semiconductor (CMOS) Field-Effect Transistor (FET) switches.

Digital vs. Analog Signal Switches

Digital switches are designed to pass (or isolate) digital signal levels and may exhibit the capability to satisfactorily pass analog signals. Examples are CBT and CBTLV switch families.

Analog switches are designed to pass (or isolate) analog signals and often exhibit good digital signal performance as well. One example is TI's TS technology.

TI offers a wide variety of signal switches, and sometimes the nomenclature can be confused to imply limited functionality for a device or family. However, it should be apparent the most important switch characteristic depends on how it is used:

- What V+ levels are present?
- What amplitude signals are required to be passed?

• What is the maximum signal distortion limit for the system?

The following are some things to consider when selecting the right analog switch.

Analog Signal Considerations

 V_+ — For noncharge-pump switches, V+ determines the analog signal amplitude that can be passed without clipping. The gate(s) of the pass transistors must be biased relative to the minimum and maximum values of the expected input voltage range. Some switches allow for biasing from two supplies, making it easy to pass both positive and negative signals. Switches with integrated charge pumps can elevate the gate voltage above V₊ (at the expense of larger I₊) and thus pass signals of a magnitude greater than V₊.

Analog Switch Overview

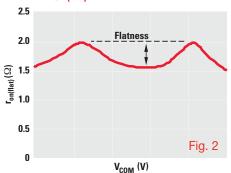
Selecting the Right TI Analog Switch (Continued)

ON-State Resistance (r_{ON}) — Because r_{ON} contributes to signal loss and degradation, low- r_{ON} tradeoffs must be considered. Non-charge pump switches achieve low r_{ON} with large pass transistors. These larger transistors lead to larger die sizes and increased C_{I/O}. This additional channel capacitance can be very significant, as it limits the frequency response of the switch. Switches using charge-pump technology can achieve low r_{ON} and C_{I/O} but require significantly higher I₊.

ON-State Resistance Flatness (r_{ON(flat)})

- Specifies the minimum and maximum value of r_{ON} over the specified range of conditions. These conditions are typically changes in temperature or supply voltage. Figure 2 is an example of $r_{ON(flat)}$.





On/Off Capacitance (C_{ON}/C_{OFF}) — Total switch and load capacitance must be considered because it can affect response time, settling time and fanout limits.

Frequency Response — All CMOS switches have an upper limit to the frequency that can be passed. No matter how low r_{ON} and $C_{I/O}$ can be maintained in the chip manufacturing process, they still form an undesired low-pass filter that attenuates the switch output signal.

Sine-Wave Distortion or Total Harmonic Distortion (THD) — These are measurements of the linearity of the device. Nonlinearity can be introduced in a number of ways (design, device physics, etc.); but typically the largest contributor is r_{ON} , which varies with $V_{I/O}$ for all types of CMOS switches. Having a low r_{ON} is important, but a flat r_{ON} over the signal range is as equally important. For signal ranges of $0 < V_{I/O} < (V_+ - 2 V)$, n-channel switches exhibit very flat r_{ON} characteristics; but r_{ON} increases very rapidly as $V_{I/O}$ approaches V_+ and VGS decreases. Parallel n-/p-channel switches offer good r_{ON} flatness for signal ranges of $0 < V_{I/O} < V_+$, with the best flatness characteristic at the highest recommended switch V_+ .

Crosstalk — There are two types of crosstalk to consider:

• Control (enable) to output — The level of crosstalk is a measure of how well decoupled the switch control signal is from the switch output. Due to the parasitic capacitance of CMOS processes, changing the state on the control signal causes noise to appear on the output. In audio applications, this can be a source of the annoying pop that is sometimes heard when switching the unit on or off.

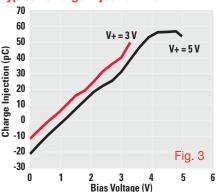
• Between switches — The level of crosstalk also is a measure of adjacent-channel rejection. As with control-to-output crosstalk, parasitic capacitance can couple the signal on one switch with that on another switch.

OFF Isolation — A measurement of OFF-state switch impedance. It is measured in dB at a specific frequency with the corresponding channel (NC to COM or NO to COM) in the OFF state.

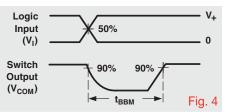
Feedthrough — This characteristic is related to the ability of the switch to block signals when off. As with crosstalk, parasitic capacitance allows high frequencies to couple through the switch, making it appear to be on.

Charge Injection (Q) — TI specifies enable-to-output crosstalk, and some competitors use this parameter. As with enable-to-output crosstalk, changing the state on the control pin causes a charge to be coupled to the channel of the transistor, introducing signal noise. It is presented in this report for a relative comparison with the competition. A graph of bias voltage vs. charge injection is displayed in figure 3 above.

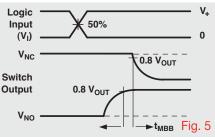
Typical Charge Injection Plot



Typical BBM Timing



Typical MMB Timing



Break-Before-Make (BBM) Time -

Guarantees that two multiplexer paths are never electrically connected when the signal path is changed by the select input. This parameter is measured under a specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO), when the control signal changes state (as shown in figure 4 above).

Make-Before-Break (MBB) Time -

Guarantees that two multiplexer paths are never open when the signal path is changed by the select input. This parameter is measured under a specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO), when the control signal changes state (as shown in figure 5 above).

Selection Tables

Analog Switch Configurations

Device	r _{on} (typ)	r _{oN} Flatness (typ)	r _{on} Mismatch (typ)	v + (v) min	v + (v) max	ESD	ON Time (ns) (typ)	OFF Time (ns) (typ)	Pins/Packages	Features
SPST										
TS5A3166	0.9	0.15	_	1.65	5.5	2 kV HBM	4.5	9	5/SC70,SOT-23, WCSP	
TS5A3167	0.9	0.15	_	1.65	5.5	2 kV HBM	4.5	9	5/SC70,SOT-23, WCSP	
TS5A4594	8	1.5	_	2.7	5.5	2 kV HBM	12	9	5/SC70,SOT-23	
TS5A4595	8	1.5	_	2.7	5.5	2 kV HBM	12	9	5/SC70,SOT-23	
TS5A4596	8	1.5	—	2.7	5.5	2 kV HBM	12	9	5/SC70,SOT-23	
TS5A4597	8	1.5	_	2.7	5.5	2 kV HBM	12	9	5/SC70,SOT-23	
TS12A4514	6.5	1	—	3	12	—	22	20	8/SOIC, 8DIP, 5SOT-23	
TS12A4515	6.5	1	_	3	12	—	22	20	8/SOIC, 8DIP, 5SOT-23	
TS12A4516	12	1.2	_	±1.65	±6	—	58	28	8/SOIC, 8DIP, 5SOT-23	Dual Supply
TS12A4517	12	1.2	_	±1.65	±6	—	58	28	8/SOIC, 8DIP, 5SOT-23	Dual Supply
TS5A1066	7.5	2.5	—	1.65	5.5	2 kV HBM	4.8	3	5/SC70,SOT-23, WCSP	
SPST x 2										
TS5A23166	0.9	0.25	0.1	1.65	5.5	2 kV HBM	4.5	8	8/US8,WCSP	
TS5A23167	0.9	0.25	0.1	1.65	5.5	2 kV HBM	4.5	8	8/US8,WCSP	
TS5A2066	7.5	3.5	0.4	1.65	5.5	2 kV HBM	5.2	2.6	8/USB, 8/SM8, 8/WCSP	
TS3A4741	0.7	0.23	0.03	1.65	3.6	—	5	4	8/SSOP/MSOP	
TS3A4742	0.7	0.23	0.03	1.65	3.6	—	5	4	8/SSOP/MSOP	
SPST x 4										
TS3A4751	0.7	0.23	0.03	1.65	3.6	4 kV HBM	5	4	14/TSSOP, SON, µQFN	
TS12A44513	6.5	1	2.5	2	12	2 kV HBM	25	20	14/TSSOP, 14/SOIC	
TS12A44514	6.5	1	2.5	2	12	2 kV HBM	25	20	14/TSSOP, 14/SOIC	
TS12A44515	6.5	1	2.5	2	12	2 kV HBM	25	20	14/TSSOP, 14/SOIC	
SPDT										
TS5A2053	7.5	1.7	0.8	1.65	5.5	2 kV HBM	5.3	1.9	8/SM8/US8	
TS5A3157	10	4	0.15	1.65	5.5	2 kV HBM	6	3.5	6/SC70,SOT-23,WCSP	
TS5A63157	4	1.5	0.05	1.65	5.5	2 kV HBM	3.4	2.8	6/SC70, SOT-23	Undershoot/Overshoot Protection
TS12A12511	5	1.3	1	±2.7	±6, +12	2 kV HBM	56	25	8/SON, 8/SOT-23, 8/MSOP	Single or Dual Supply
TS5A3153	0.8	0.09	0.05	1.65	5.5	2 kV HBM	12.5	8.5	8/US8/WCSP	
TS5A3154	0.8	0.09	0.05	1.65	5.5	2 kV HBM	5.2	9.5	8/US8/WCSP	
TS5A9411	5.3	0.03	2	2.25	5.5	2 kV HBM	9	7	6/SC70	
TS5A3159	0.75	0.15	0.1	1.65	5.5	2 kV HBM	20	15	6/SC70, SOT-23	
TS5A3159A	0.7	0.1	0.05	1.65	5.5	2 kV HBM	12	5	6/SC70,SOT-23,WCSP	



Analog Switch Configurations (Continued)

Device	r _{on} (typ)	r _{on} Flatness (typ)	r _{oN} Mismatch (typ)	^{v + (v)} min	^{v + (v)} max	ESD	ON Time (ns) (typ)	OFF Time (ns) (typ)	Pins/Packages	Features
SPDT (contin	ued)									
TS5A3160	0.7	0.1	0.05	1.65	5.5	2 kV HBM	3.5	3.5	6/SC70, SOT-23	
TS5A4624	0.7	0.1	0.05	1.65	5.5	2 kV HBM	12	5	6/SC70	
TS5A6542	0.5	0.1	0.05	2.25	5.5	±15 kV Contact (IEC L-4)	12.5	9.5	8/WCSP, μQFN	
TS5A12301E	0.5	0.1	0.05	2.25	5.5	±15 kV Air-Gap	72	80	6/WCSP (0.4mm pitch)	1.8-V Logic Compatible Logic Threshold Independently of V+
SPDT x 2										
TS5A23157	10	4	0.15	1.65	5.5	2 kV HBM	5.7	3.8	10/MSOP, µQFN	
TS5A623157	4	4	0.15	1.65	5.5	2 kV HBM	3.5	2.8	10/MSOP, µQFN	Overshoot/Undershoot Protection
TS5A23159	0.7	0.1	0.05	1.65	5.5	2 kV HBM	8	5	10/MSOP/QFN	
TS3A24157	0.5	0.01	0.05	1.65	3.6	2 kV HBM	20	12	10/ μQFN, VSSOP	Ultra-Low
TS3A24159	0.26	0.01	0.01	1.65	3.6	2 kV HBM	20	12	10/WCSP, SON, VSSOP	R _{ON}
TS5A26542	0.5	0.1	0.05	2.25	5.5	±15 kV Contact (IEC L-4)	12.5	9	12/WCSP	
TS3A225E	0.1	_	_	2.7	4.5	±8kV Contact Discharge (IEC L-4)	21	21	16/WCSP, QFN	Autonomous Audio Headset Switch
TS3A26746E	0.08	_	_	3	3.6	±8kV Contact Discharge (IEC L-4)	150	5	6/WCSP	2 X 2 Crosspoint Switch for Audio Applications
TS5A22362	0.52	0.076	0.04	2.3	5.5	2.5 kV HBM	27	13	10/WCSP, 10/SON, VSSOP	Negative Rail Capability
TS5A22364	0.52	0.076	0.04	2.3	5.5	2.5 kV HBM	27	13	10/WCSP, 10/SON, VSSOP	Negative Rail Capability, Click Pop Suppression
TS5A22366	0.7	0.135	0.05	2.25	5.5	2.5 kV HBM	193	182	12/WCSP (0.4mm pitch), 10/µQFN	Negative Rail Capability
SPDT x 4										
TS3A5018	7	5	0.3	1.65	3.6	2 kV HBM	3.5	2	16/SOIC, SSOP, (QSOP), TSSOP, TVSOP, SON	
TS3A44159	0.3	0.07	0.045	1.65	4.3	2 kV HBM	17	12	16/TSSOP, SON, µQFN	
SPDT x 6										
TS3A27518E	4.4	0.91	0.3	1.65	3.6	±6 kV Contact (IEC L-3)	14.1	16.1	24BGA, SON	
SP3T										
TS5A3359	0.7	0.1	0.1	1.65	5.5	2 kV HBM	2.5	6	8/US8, 8/WCSP	
SP4T x 2										
TS3A5017	11	7	1	2.3	3.6	2 kV HBM	5	1.5	16/SOIC, SSOP, (QSOP), TSSOP, TVSOP, SON, µQFN	

New products are listed in bold red.

Selection Tables

Analog Switch Configurations (Continued)

Device	r _{on} (typ)	Normally Closed (NC)	Normally Open (NO)	Enable Pin	Break Before Make (BBM)	Make Before Break (MBB)	Over-/Undershoot Protectiom	I _{OFF}
SPST								
TS5A3166	0.9		Х					Х
TS5A3167	0.9	Х						Х
TS5A4594	8		Х					
TS5A4595	8	Х						
TS5A4596	8		Х					
TS5A4597	8	Х						
TS12A4514	6.5		Х					
TS12A4515	6.5	Х						
TS12A4516	12		Х					
TS12A4517	12	Х						
TS5A1066	7.5		Х					
SPST x 2								
TS5A23166	0.9		X(2)					Х
TS5A23167	0.9	X(2)						Х
TS5A2066	7.5		X(2)					
TS3A4741	0.7		X(2)					
TS3A4742	0.7	X(2)						
SPST x 4								
TS3A4751	0.7		X(4)					
TS12A44513	6.5	X(2)	X(2)					
TS12A44514	6.5		X(4)					
TS12A44515	6.5	X(4)						
SPDT								
TS5A2053	7.5			Х				
TS5A3157	10							
TS5A63157	4				Х		Х	Х
TS12A12511	5				Х			
TS5A3153	0.08			Х	Х			Х
TS5A3154	0.08			Х		Х		Х
TS5A9411	5.3				Х			
TS5A3159	0.75				Х			
TS5A3159A	0.7				Х			Х
TS5A3160	0.7				Х			Х

Selection Tables

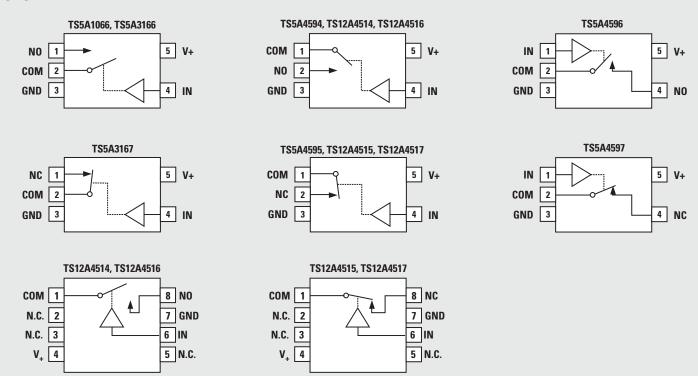
Analog Switch Configurations (Continued)

Device	r _{on} (typ)	Normally Closed (NC)	Normally Open (NO)	Enable Pin	Break Before Make (BBM)	Make Before Break (MBB)	Over-/Undershoot Protectiom	I _{OFF}
SPDT (continued	d)							
TS5A4624	0.7				Х			Х
TS5A6542	0.5				Х			
TS5A12301E	0.5				Х			Х
SPDT x 2								
TS5A23157	10				Х		Х	Х
TS5A623157	4				Х		Х	
TS5A23159	0.7				Х			Х
TS3A24157	0.5				Х			
TS3A24159	0.26				Х			
TS5A26542	0.5				Х			
TS3A225E	0.1				Х			Х
TS3A26746E	0.08				Х			Х
TS5A22362	0.52				Х			
TS5A22364	0.52				Х			
TS5A22366	0.7				Х			
SPDT x 4								
TS3A5018	7			Х				
TS3A44159	0.3				Х			
SPDT x 6								
TS3A27518E	4.4			Х				Х
SP3T								
TS5A3359	0.7				Х			Х
SP4T x 2								
TS3A5017	11			Х				

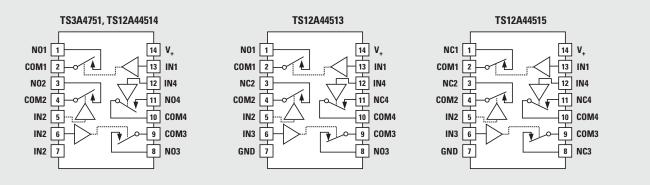
New products are listed in bold red.

Pinouts

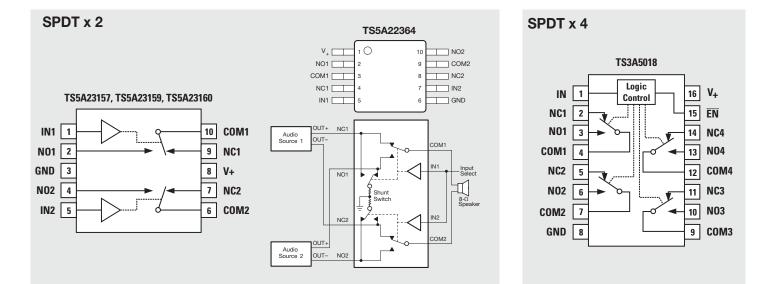
SPST



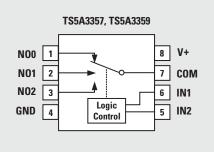
SPST x 4

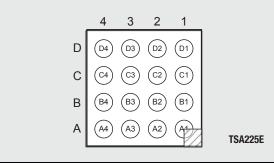






SP3T

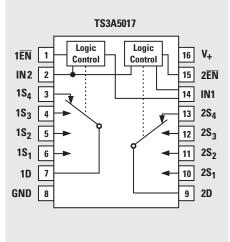




	4	3	2	1
D	/MIC_PRESENT	TIP_SENSE	MICp	MICn
С	RING2	GND ⁽¹⁾	VDD ⁽¹⁾	RING2_SENSE
В	SLEEVE	GND ⁽¹⁾	VDD ⁽¹⁾	SLEEVE_SENSE
Α	DET_TRIGGER	ADDR_SEL	SDA	SCL

YZP Package (Top View) 2 TS3A26746E 1 A Α SEL В В MIC SLEEVE C GND RING2 C

SP4T x 2



2

V+

Applications

2x2 Crosspoint Switch for Audio Applications TS3A26746E



Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3a26746e

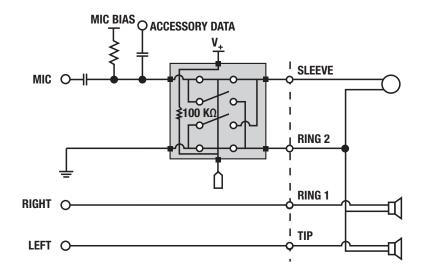
Key Features

- Superior PSRR performance (-75 dB)
- Control input is 1.8 V logic compatible
- ESD performance (SLEEVE, RING2) o ±8-kV contact discharge (IEC 61000-4-2)
- 6-bump, 0.5 mm pitch CSP package (1.45 x 0.95 x 0.5 mm)

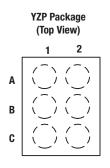
Applications

- Cellular phones
- Digital still cameras
- PDAs
- Portable instrumentation
- Portable navigation devices

The TS3A26746E is a 2 × 2 cross-point switch that is used to interchange the ground and MIC connections on a headphone connector. The ground switch has an ultra low r_{ON} of <0.1 Ω to minimize voltage drop across it, preventing undesired increases in headphone ground reference voltage. The switch state is controlled via the SEL input. When SEL=High, GND is connected to RING2 and MIC is connected to SLEEVE. When SEL=Low, GND is connected to SLEEVE and MIC is connected to RING2. An internal 100k pull-up resistor on the SEL input sets the default state of the switch. This device effectively switches the GND and MIC lines to the appropriate coordinates with minimal signal distortion and power loss.







	1	2
Α	SEL	V+
В	MIC	SLEEVE
C	GND	RING2

Applications

Audio Headset Switch Device

TS3A225E



Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3a225e

Key Features

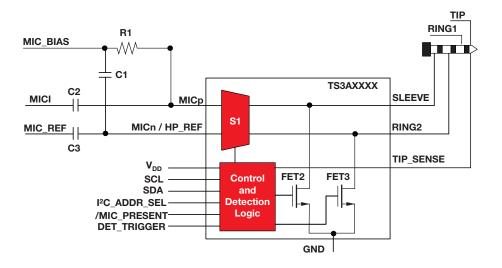
- V_{DD} range = 2.7 V to 4.5 V
- Break-before-make stereo jack switches
- Ultra-low resistance ground FET switches (< 100 mΩ)
- HDA compatible MIC present indicator
- Optional I²C switch control
- 95 dB audio isolation
- IEC ESD protection on stereo jack pins
- ±8-kV contact discharge (IEC 61000-4-2)
- ESD performance tested per JESD 22 (all pins)
- 2-kV Human Body Model (HBM) (A114-B, Class II)

Applications

- Mobile phones
- Mobile music players
- Notebook computers
- Mobile audio applications

The TS3A225E is an audio headset switch device. The device detects the presence of an analog microphone and switches a system analog microphone pin between different connectors in an audio stereo jack. The microphone connection in a stereo connector can be swapped with the ground connection depending on manufacturer. When the device detects a certain configuration, it automatically connects the microphone line to the appropriate pin. The device also reports the presence of an analog microphone on an audio stereo jack.

In some systems, it is desirable to connect the stereo jack pin to ground. The TS3A225E provides two internal low resistance (<100 m) FET switches for ground shorting.



		YFF Pa (Top	ickage View))
	4	3	2	1
D	(D4)	(D3)	(D2)	(D1)
C	(C4)	(C3)	(C2)	(C1)
В	(B4)	(B3)	(B2)	(B1)
A	(A4)	(A3)	(A2)	

Applications

±6 V, +12 V 5-Ω SPDT Analog Switch TS12A12511

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts12a12511

Key Features

- ±2.7 V to ±6 V dual-supply operation
- +2.7 V to +12 V single-supply operation
- ON-state resistance: 8 Ω max with ±5 V supply
- Low ON and OFF-leakage currents: ±1 nA at 25°C, ±50 nA at 85°C
- Fast switching speed: t_{ON}=115 ns, t_{OFF}=56 ns (±5 V supply)
- Break-before-make operation
- +3.3 V, +5 V compatible digital control inputs
- Available in 8-pin MSOP, SOT, QFN packages

Applications

- Automatic test equipment
- Power routing
- Communication systems
- Data acquisition systems
- Sample-and-hold systems
- Relay replacement
- Battery-powered systems

The TS12A12511 is a single-pole double-throw (SPDT) analog switch capable of passing signals with swings of 0 to 12 V or –6 to 6 V. This switch conducts equally well in both directions when it is on. It also offers a low ON-state resistance of 5 (typical), which is matched to within one between channels. The max current consumption is <1 μ A and –3 dB bandwidth is >93 MHz. The TS12A12511 exhibits break-before-make switching action, preventing momentary shorting when switching channels. This device is available packaged in an 8-lead MSOP, 8-lead SOT-23, and 8-pin QFN.

TS12A12511

3

8

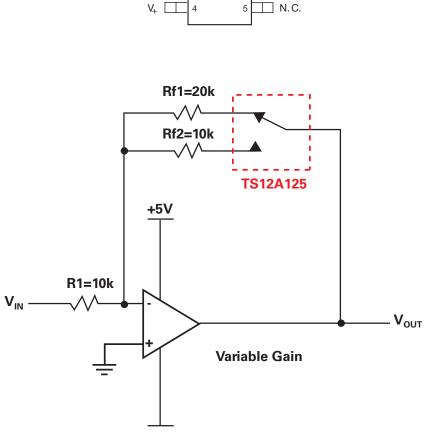
NO NO

______V_

сом Г

NC [

GND [



TS12A12511 variable gain.

Applications

Single 5-Ω SP3T Analog Switch—5-V/3.3-V 3:1 Analog Multiplexer/Demultiplexer TS5A3357

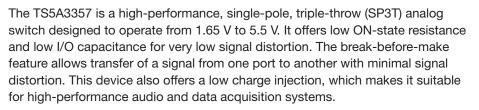
Get samples, data sheets and app reports at: www.ti.com/sc/device/ts5a3357

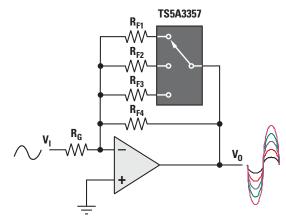
Key Features

- Specified break-before-make switching
- Low ON-state resistance
- High bandwidth
- Control inputs are 5.5-V tolerant
- · Low charge injection
- Excellent ON-state resistance
 matching
- Low total harmonic distortion
- 1.65- to 5.5-V single-supply operation

Applications

- High-performance analog audio switching
- Audio signal routing/MUXing from three sources
- Simplified large PCB routing, especially on space-constrained PCBs





Amplifier gain adjustment.

Dual SP4T Analog Switch TS3A5017

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3a5017

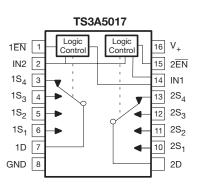
Key Features

- Isolation in the powered-down mode, V+ = 0
- Low ON-state resistance
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion (THD)
- 2.3-V to 3.6-V single-supply operation
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD performance tested per JESD 22

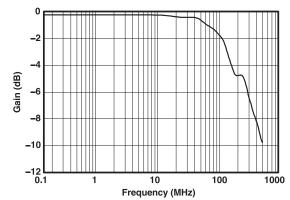
Applications

- · Sample and hold circuits
- Battery-powered equipment
- Audio and video signal routing
- Communication circuits

The TS3A5017 is a dual single-pole quadruple-throw (4:1) analog switch that is designed to operate from 2.3 V to 3.6 V. This device can handle both digital and analog signals, and signals up to V+ can be transmitted in either direction.



t_{ON} and t_{OFF} vs. Temperature (V+ = 3.3 V)



Applications

Dual/Single SPDT Analog Switches with Input Logic Translation and IEC ESD TS5A26542, TS5A6542, TS5A12301E

Get samples, data sheets and app reports at: www.ti.com/sc/device/PARTnumber

Key Features

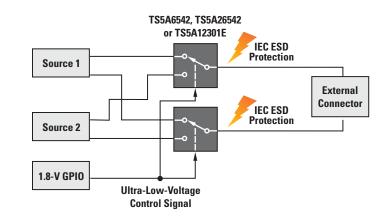
- Specified break-before-make switching
- Low ON-state resistance (0.75 Ω typ)
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion
- 2.25- to 5.5-V power supply (V₊)
- 1.8 V logic compatible thresholds
- o TS5A6542 and TS5A26542: V_{IO} bias used to allow low threshold control voltage
- o TS5A12301E: Low threshold voltage independent of $V_{\rm +}$ and no use of additional bias $(V_{\rm IO})$
- No need for separate translation devices
- ESD performance tested per JESD 22
 - o 2000-V Human Body Model (HBM) (A114-B, Class II)
 - o 1000-V charged-device model (C101)
- Common inputs • ±15-kV IEC61000-4-2,
 - contact discharge for TS5A26542 and TS5A6542
 - Comm inputs can be interfaced to the external world due to IEC ESD compliance
 - No need for separate ESD devices

Applications

- Cell phones
- PDAs
- Portable instrumentation

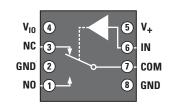
The TS5A26542, TS5A6542, and TS5A12301E are single-pole double-throw (SPDT) analog switches that are designed to operate from 2.25 V to 5.5 V. The TS5A26524 is a dual SPDT, whereas the TS5A6542 and TS5A12301E are single SPDT switches. The devices offer a low ON-state resistance with an excellent channel-to-channel ON-state resistance matching, and the break-before-make feature to prevent signal distortion during the transferring of a signal from one path to another.

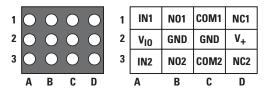
These devices have excellent total harmonic distortion (THD) performance and consume very low power. These features make them suitable for portable audio applications. All of the switches can be controlled by 1.8-V signals.



IEC ESD protection on analog switch outputs.

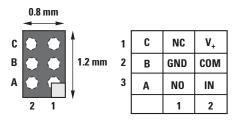
Package Pinouts





TS5A6542 WCSP (YZP) package (bottom view).

TS5A26542 WCSP (YZP) package (bottom view).



TS5A12301E WCSP (YFP) package (top view).

Applications

0.6-Ω Dual Analog Switches

TS5A22362/4/6

Get samples, data sheets and app reports at: www.ti.com/sc/device/PARTnumber

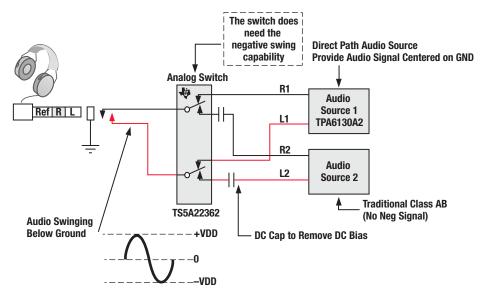
Key Features

- Negative signaling capability: Analog I/O range = V₊ -5.5 V to V₊
- Internal shunt switch prevents audible click-and-pop when switching between two sources (TS5A22364 only)
- Low ON-state resistance (0.65-Ω typ)
- Low charge injection
- Excellent ON-State resistance matching
- 2.3-V to 5.5-V power supply (V₊)
- TS5A22362/TS5A22364 packaging options:
 - 10-WCSP (0.5 mm pitch YZP)
 1.9 x 1.4
 SON-10 (DRL) 3 x 3
 VSSOP-10 (DGS) 4.9 x 3

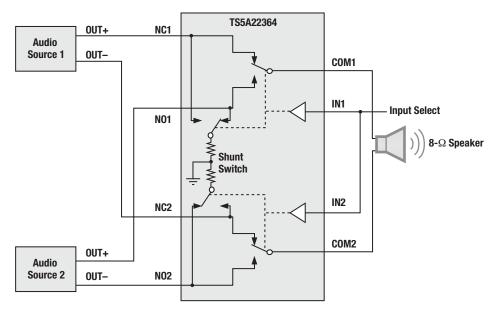
Applications

- Cell phones
- PDAs
- Portable instrumentation
- Audio routing

The TS5A22362, TS5A22364, and TS5A22366 are dual single-pole double-throw (SPDT) analog switches that are designed to operate from 2.25 to 5.5 V. The devices feature negative signal capability that allow signals below ground to pass through the switch without distortion. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance make these switches ideal for audio applications.



Direct path amplifier - negative rail capability.



TS5A22364 – negative rail capability and click-pop suppression



		V _{cc} (V	(_{ac}	r _{on}			Off			
Device	Configuration	(min) (V)	(max) (V)	(typ) (Ω)	Bandwidth (MHz)	Crosstalk (dB)	Isolation (dB)	I _{CC} (I _{DD}) (typ)(μΑ)	Pins/ Packages	Description
Video Switch										
TS3DV20812	8-channel SPDT	2.25	3.6	4	1100	-35	-20	250	36/QFN	2 Gbps Differential Switch, 8-Ch with 3-Side Band Signals
TS3DV421	8-channel SPDT	1.5	2.1	12.5	1900	-50	-50	230	42/QFN, 48/TVSOP	4-Ch Differential 8:16 Mux Switch for DVI/ HDMI
TS3DV520E	10-channel SPDT	3	3.6	4	950	-37	-37	250	42/QFN, 56/QFN	5-Ch Differential 10:20 Mux Switch for DVI/HDMI
TS3DV621	12-channel SPDT	3	3.6	8	2200	-43	-42	300	42/QFN,	12-Channel 1:2 MUX/DEMUX Switch with Integrated 4-Channel Sideband Signal Switching
TS3V712E	7-channel SPDT	3	3.6	3	1360	-50	-38	200	32/QFN	7-Ch Video Switch
TS3V712EL	7-channel SPDT	3	3.6	4	1300	-47	-38	200	32/WQFN	7-Ch, 1:2 Video Switch With Integrated Level Shifters
TS3V713EL	7-channel SPDT	3	3.6	4	1300	-50	-40	200	32/WQFN	7-Ch, 1:2 Video Switch With Integrated Level Shifters
SLAN Switch										
TS3L500	8-channel SPDT	3	3.6	4	1100	-37	-37	250	56/QFN	16-Bit to 8-Bit SPDT Bigabit LAN Switch with Low Flat $\ensuremath{r_{\text{ON}}}$
TS3L500AE	8-channel SPDT	3	3.6	4	950	-37	-37	250	56/QFN	16-Bit to 8-Bit SPDT Gigabit LAN Switch with LED Switch and Enhanced ESD Protection
TS3L501E	16-channel SPDT	3	3.6	4	600	-37	-37	250	42/WQFN	16-Bit To 8-Bit Multiplexer/Demultiplexer Gigabit Ethernet LAN Switch with Power Down Mode
PCI Express S	Signal Switch									
TS2PCIE2212	4-channel SPDT	1.7	1.9	10	1250	-39	-38	160	48/PBGA	PCle Gen-I Signal Switch
TS2PCIE412	16-channel SPDT	1.5	2.1	12	2100	-81	-74	—	42/QFN	x2 4-Ch PCle 2:1 Multiplexer/Demultiplexer PCle Gen-I Switch
Network Sign	al Switch									
TS5N118	Cross-Point	4.75	5.25	3	25	-50	-50	10000	16/SSOP, TSSOP	1-Bit 1-of-8 FET Multiplexer/Demultiplexer for DS1 and DS3 Signal Levels
TS5N214	Cross-Point	4.75	5.25	3	25	-50	-50	10000	16/SSOP, TSSOP	2-Bit 1-of-4 FET Multiplexer/Demultiplexer for DS1 and DS3 Signal Levels
TS5N412	Cross-Point	4.75	5.25	3	25	-50	-50	10000	16/SSOP, TSSOP	4-Bit 1-of-2 FET Multiplexer/Demultiplexer for DS1 and DS3 Signal Levels
USB 2.0 Signa	al Switch								10/001	
TS3USB221	2-channel SPDT	2.3	3.6	6	1100	-40	-41	30	10/SON, 10/QFN	High-Speed USB 2.0 (480 Mbps) 1:2 Mux/ Demux Switch with Single Enable High-Speed USB 2.0 (480 Mbps) 1:2 Mux/
TS3USB221A	2-channel SPDT	2.3	3.6	3	900	-39	-40	30	10/QFN	Demux Switch with Single Enable with 12kV HBM ESD Protection
TS3USB31	2-channel SPST	3	4.3	6	1220	-53	-30	1	8/µQFN	High-Speed USB 2.0 (480 Mbps) 1:1 Switch
TS3USB31E	2-channel SPST	2.25	4.3	6.4	1100	-53	-30	1	8/µQFN	High-Speed USB 2.0 (480 Mbps) 1:1 Switch with 15kV HBM ESD Protection
TS5USBA224	2-channel SPDT	2.7	5.5	4	650	-31	-22	6	10/µQFN	USB 2.0 High-Speed (480 Mbps) and Audio Switches with Negative Signal Capability and 1.8-V Logic Compatibility
TS3USB30	2-channel SPDT	3	4.3	6	955	-56	-39	1	10/UQFN	High-Speed USB 2.0 (480 Mbps) 1:2 Mux/Demux Switch with Single Enable
TS3USB30E	2-channel SPDT	3	4.3	6	900	54	-40	1	10/VSSOP, 10/TQFN	High-Speed USB 2.0 (480 Mbps) 1:2 Mux/Demux Switch with Single Enable with 15kV HBM ESD Protection
										New products are listed in bold red.

Selection Tables

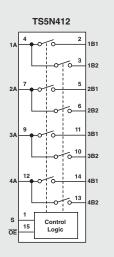
		V _{cc} (V _{DD})	r _{on}			Off	I _{cc} (I _{dd})		
Device	Configuration	(min) (V)	(max) (V)	(typ) (Ω)	Bandwidth (MHz)	Crosstalk (dB)	Isolation (dB)	(typ) (μA)	Pins/Packages	Description
USB 2.0 Signal Switch continued										
TS3DS10224	2-channel 2:4 MUX	3	3.6	10	1200	-30	-30	50	20/QFN	High-Speed 2:4 Differential Multiplexer / Demultiplexer
TS3USBA225	2-channel SP3T	2.7	4.3	6.5	1900	-45	-35	25	12/UQFN	USB 2.0 High-Speed (480 Mbps) and Audio Switches with Negative Signal Capability and 1.8-V Logic Compatibility and Power-Down Mode
TS3USB3200	3-channel SPDT	2.7	4.3	5.7	6000	-83	-83	30	16/QFN	DPDT USB 2.0 Hligh-Speed (480Mbps) and Mobile High- Definition Link (MHL) Switch with ID Select and Flexible Power Control
DDR Memory N	Iodule Switches									
TS2DDR2811	8-channel SPST	3	3.6	4	1100	-37	-37	250	20/BGA	1-GHz Bandwidth, 8-Channel SPST Switch for DDR2
TS3DDR3812	16-chanel SPDT	3	3.6	8	1675	-43	-42	300	42/WQFN	12-Channel, 1:2 MUX/DEMUX Switch for DDR3 Applications

				V _{cc} ((V _{dd})				Off			
Device	Configuration		nCH	(min) (V)	(max) (V)	r _{0N} (max) (Ω)	Bandwidth (MHz)	Crosstalk (dB)	Isolation (dB)	(I _{DD}) Max (μA)	Pins/ Packages	Description
Smart Sw	vitch											
TSU5511	Dual SP3T + SPST	Audio Mic USB UART	2 1 2 2	-1.3 0 0 0	1.3 2.3 3.6 4.4	6 12 10 61	788 573 830 295	-120 -125 -42 -98	-100 -37 -20 -100	70	20 WCSP	Micro-USB Connector to UART and Audio Switches with ID Detection and Charger Detection
TSU6111/A	Dual SP2T	USB UART	2	0	4.4 4.4	18 18	950 950	-32 -32	-26 -26		16/QFN	Micro-USB Connector to UART and USB Switches with ID Detection and Charger Detection
TSU6712/A	Dual SP3T + Dual SPST	Audio Mic USB UART	2 1 2 2	-0.8 0 -0.5 0	0.8 2.3 2 4.4	5.5 70 18 15	100 40 400 480	-100 -100 -78 -40	-100 -95 -58 -24	150	25/WCSP	Micro-USB connector to UART, USB, Audio and Video Switches with ID Detection and Charger Detection
TSU5611	Dual SP3T + SPST	Audio Mic USB UART	2 1 2 2	-1.3 0 0 0	1.3 2.3 3.6 3.6	3.8 9 4.5 4.5	900 573 920 920	-100 -100 -40 -40	-100 -55 -29 -29	60	20/WLBGA	DP3T Switch with Impedence Detection Micro-USB Switch To Support USB, UART, Audio, and Charger Detection
TSU8111	Dual SPDT + charger	USB UART	2	0 0	3.6 3.6	8 8	920 920	-32 -32	-26 -26	100	20/BGA	Single-Cell Charger and USB SP2T Switch Supports USB & UART
BQ24392	Dual SPST + charger detection	USB	2	0	3.6	8	920	-32	-26	250	10/QFN	Charger Detection Device with High Speed USB Switch Battery Charger Specification v1.2
TSU6721	Dual SP3T + SPDT +SPST	USB UART Audio Mic Load Switch	2 2 1	0 0 -1.5 0 4.0	3.6 3.6 +1.5 2.3 6.5	8 8 2 40 0.15	920 920 450 40	-32 -32 -85 -85	26 26 100 95	TBD	25/BGA	MCPC Compatible USB Port Multimedia Switch Supports USB, UART, Audio, ID, MIC, and Load Switch

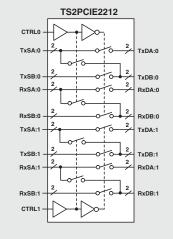
Preview products are listed in bold blue. New products are listed in bold red.

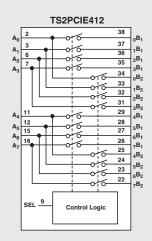


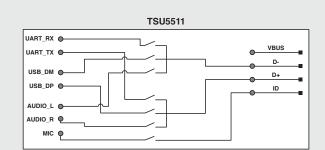
Network

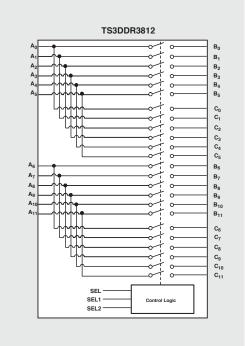


PCI Express[®]









Applications

12-Ch 1:2 Mux/DeMux for DVI/HDMI and DP Applications w/4-Ch Sideband Switching TS3DV621



Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3dv621

Key Features

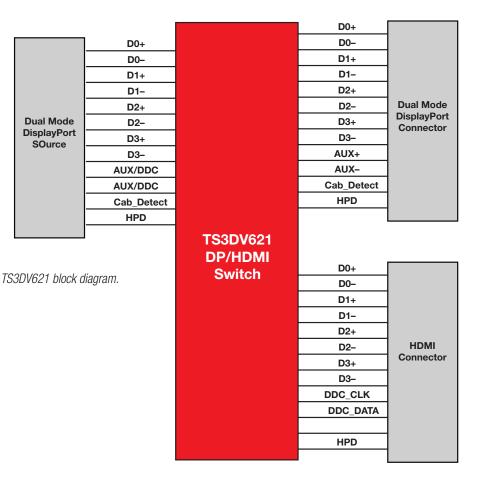
- Compatible with HDMI v1.4, DVI 1.0 and display port 1.1a high-speed digital interface
 - Wide bandwidth of 2.2 GHz
 - Four integrated side band signals switching
 - o Support all video formats up to 1080 P and SXGA (1280 x 1024 at 75 Hz)
 - HDCP compatible
- Low and flat ON-state resistance (r_{ON} = 8 Ω typ)
- Low input/output capacitance (C_{ON} = 4 pF typ)
- + V_{CC} operating range from 3 V to 3.6 V
- Rail-to-rail switching on data I/O ports (0 to V_{cc})
- Dedicated enable logic supports Hi-Z mode
- I_{OFF} protection prevents current leakage in powered down state
- ESD performance tested per JESD22
 o 2-kV human body model (A114B, Class II)
 - o 1-kV charged device model (C101)
- 42-pin RUA package (9 x 3.5 mm, 0.5 mm pitch)

Applications

- HDMI/DVI and DP signal switching
- Laptop, desktop and tablet computers and docking stations
- LCD TVs, A/V receivers, multimedia hubs/consoles

The TS3DV621 is a multiple SP4T switch with impedance detection. The switch features impedance detection, which supports the detection of various accessories that are attached through DP and DM. This device is fully controlled using I^2C and enables USB data, stereo and mono audio, video, microphone, and UART data to use a common connector port.

Power for this device is supplied through V_{BAT} of the system or through V_{BUS} when attached. The switch can be controlled through I²C. JIG and BOOT pins are used when a USB, UART JIG cable is used to test during development and manufacturing.



Applications

7-Channel VGA Mux/DeMux with Level Shifting TS3V712EL

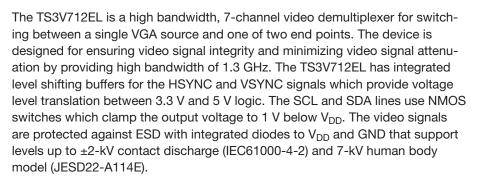
Get samples, data sheets, EVMs and app reports at: www.ti.com/sc/device/ts3v712el

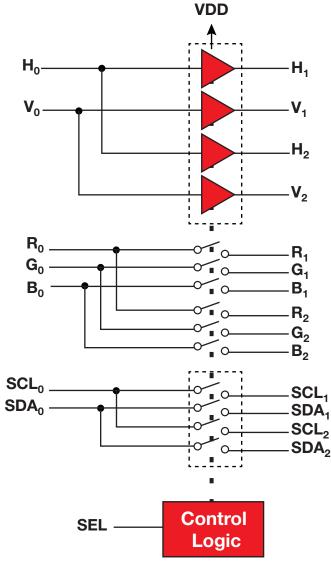
Key Features

- Supports 7-channel VGA signals (R,G,B, HSYNC, VSYNC, DDC CLK, and DDC DAT) integrated level shifting buffers for HSYNC and VSYNC
- Operating voltage range
 o V_{DD} = 3.3 V ± 10%
 o V_{DD}_5 = 5 V ± 10%
- High bandwidth of 1.3 GHz (-3 dB)
- R,G,B switches
 or_{ON} = 4 Ω (typ)
 - $o_{CON} = 8 \text{ pF (typ)}$
- Voltage clamping NMOS switches for SCL and SDA channels
- ESD performance (14 pins on port 1 and port 2)
 ±2-kV IEC61000-4-2, contact discharge
 - o 7-kV human body model per JESD22-A114E
- ESD performance (all pins)
 o 3-kV human body model per JESD22-A114E
- 32-pin QFN package (RTG) (6 mm x 3 mm)

Applications

- Notebook computers
- Docking stations
- KVM switches





TS3V712EL block diagram.

NEW

Applications

7-Channel 7:14 SPDT VGA Signal Switch with Level Shifter TS3V713EL

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3v713el

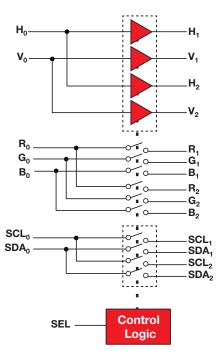
Key Features

- High bandwidth of 1.3 GHz (typ)
- Seven channels for VGA signal (R,G,B, VSYNC, HSYNC, DDC1, DDC2
- Integrated level shifting for HSYNC, VSYNC
- I/O capacitance of 4 pF
- P2P with pericom PI3V713

Applications

- Notebook computer
- Analog VGA peripheral ports
- Panel LVDS bus MUX
- Video/audio switching
- High speed logic data I/O MUX

The TS3V713EL is a high bandwidth, 7-channel video multiplexer/demultiplexer for switching between a single VGA source and one of two end points. The device is designed for ensuring video signal integrity and minimizing video signal attenuation by providing high bandwidth of 1.3 GHz. The TS3V713EL has integrated level shifting buffers for the HSYNC and VSYNC signals which provide voltage level translation between 3.3 V and 5 V logic. The SCL and SDA lines use NMOS switches which clamp the output voltage to 1 V below V_{DD}. The video signals are protected against ESD with integrated diodes to V_{DD} and GND that support levels up to ±2-kV contact discharge (IEC61000-4-2) and 8-kV human body model (JESD22-A114E).



8:16 Mux/DeMux for Gigabit Ethernet LAN TS3L501E

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3l501e

Key Features

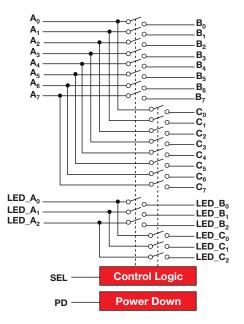
- Low bit-to-bit skew (t_{SK(o)} = 100 ps max)
- Low and flat ON-state resistance o $r_{ON} = 4 \Omega$ typ, $r_{ON(FLAT)} = 0.5 \Omega$ typ
- Low input/output capacitance
 C_{ON} = 8 pF typ
- ESD performance (A, B, C, LED pins)
 ±4-kV IEC61000-4-2, contact
 - o ±4-kV IEC61000-4-2, contact discharge
 - 6-kV human body model (HBM)
- 42-pin QFN package (RUA) –
 9 mm x 3.5 mm
- Half that of direct competition
- Allows for low power loss and THD
- Low capacitance ensure great signal BW
- Eliminates need for external ESD
- 37% size decrease from TS3L500AE

Applications

- 10/100/1000 Base-T signal switching
- Differential (LVDS, LVPECL) signal switching
- Audio/video switching
- Hub and router signal switching

The TS3L501E is a 16-bit to 8-bit multiplexer/demultiplexer LAN switch with a single select (SEL) input and Power down Mode input. The device provides additional I/Os for switching status indicating LED signals and includes high ESD protection. SEL input controls the data path of the multiplexer/demultiplexer. Power down input can put

the device into the standby mode for minimizing current consumption per mode selection. The device provides a low and flat ON-state resistance (r_{ON}) and an excellent ON-state resistance match. Low input/output capacitance, high bandwidth, low skew, and low crosstalk among channels make this device suitable for various LAN applications, such as 10/100/1000 Base-T. This device can be used to replace mechanical relays in LAN applications. It also can be used to route signals from a 10/100 Base-T Ethernet transceiver to the RJ-45 LAN connectors in laptops or in docking stations. It is characterized for operation over the free-air temperature range of -40°C to 85°C.



NEW

Applications

High-Speed USB/Audio Switch TS5USBA224

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts5usba224

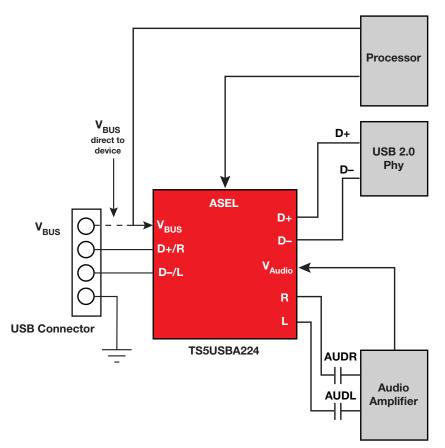
Key Features

- Powered from V_{AUDIO} (3.3 V typ)
- V_{BUS} input detects data cable connection and automatically switches to USB path (if A_{SEL} = L)
- Manual switching to audio path (if A_{SEL} = H)
- 1.8-V logic threshold compatibility for digital inputs
- USB channels: 4-Ω R_{ON}
- Audio channels: 3- Ω R_{ON}
- High bandwidth (650 MHz) for USB path
- Negative rail signaling support for audio path
- Total harmonic distortion <0.05%
- 10-µQFN (1.8mm × 1.4mm)

Applications

- Notebook computers
- Analog VGA peripheral ports

The TS5USBA224 is a double-pole, double throw (DPDT) multiplexer that includes a low-distortion audio switch and a USB 2.0 High-Speed (480 Mbps) switch in the same package. This configuration allows the system designer to use a common connector for audio and USB data. The audio switch is designed to allow audio signals to swing below ground which makes this common connector configuration possible. The TS5USBA224 is powered up using V_{AUDIO}. When A_{SEL}=High, the audio path is selected regardless of the logic level at V_{BUS}. If A_{SEL}=Low and V_{BUS}=High, the USB path is selected. Otherwise if A_{SEL}=Low and V_{BUS}=Low, the audio path is selected. The TS5USBA224 also features shunt resistors on the audio path to reduce clicks and pops that may be heard when the audio switches are selected.



TS5USBA224 block diagram.

NEW

Applications

High-Speed 2:4 Differential Multiplexer / De-multiplexer TS3DS10224

PREVIEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3ds10224

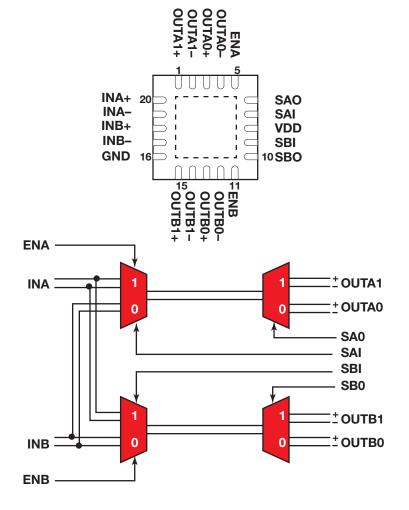
Key Features

- Flexible configurations:
 Single 1 to 4
 Dual 1 to 2
 Fan-out 1 to 2
- High BW (1.2 GHz typ)
- Low r_{ON} and C_{ON}:
 o 10 Ω r_{ON} typ
 o 8 pF C_{ON} typ
- ESD performance (I/O pins)
 ±8-kV contact discharge (IEC61000-4-2)
 - 2-kV human body model per JESD22-A114E (to GND)
- ESD performance (all pins)
 o 2-kV human body model per JESD22-A114E
- Small QFN package (3 x 3, 0.4-mm pitch)

Applications

- Notebook computers
- PDA/ebook/tablet
- Display port auxiliary channel multiplexing
- USB 2.0 multiplexing

The TS3DS10224 is a 2:4 bidirectional multiplexer for high-speed differential and single ended signal applications (up to 720 Mbps). The TS3DS10224 can be used in a 1:4 or dual 1:2 multiplexer/demultiplexer configuration. The TS3DS10224 offers a high BW of 1.2 GHz with channel R_{ON} of 13 Ω (typ). The TS3DS10224 can also be used to fan out a differential or single ended signal pair to two ports simultaneously (fan-out configuration). The BW performance is lower in this configuration. The TS3DS10224 operates with a 3 to 3.6V power supply. It features ESD protection of up to ±8-kV contact discharge and 2-kV human body model on its I/O pins. The TS3DS10224 provides fail-safe protection by isolating the I/O pins with high impedance when the power supply (VCC) is not present.



TS3DS10224 block diagram.

Applications

DP3T USB 2.0 High-Speed (480 Mbps) and Audio Switches with Negative Signal Capability TS3USBA225



Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3usba225

Key Features

- High-speed USB switch (D0 \pm and D1 \pm) • 6.5 Ω R_{DSON} maximum • 3 pF C_{ON} maximum • 1.9 GHz bandwidth (-3 dB) • V_{I/O} accepts signals up to 4.3 V (independent of V_{CC})
- Audio switch (L&R)

 2.5 Ω R_{DSON} typical
 Negative rail capability
 Low THD: <0.05%
 Internal shunt resistors for click-and-pop reduction
- 2.7 V to 4.3 V operating power supply (V_{CC})
- 1.8-V compatible control input (SEL1 and SEL2) threshold
- Minimized current consumption (~2 µA) in power-down mode
- Power-off protection: all I/O pins are high-Z when V_{CC}=0V
- ESD performance tested per JESD 22
 o 2000-V human body model (A114-B, Class II)
 o 1000 V charged device model (C101)
- 12-pin RUT package
 02×1.7 mm, 0.4 mm pitch

Applications

- Cell phones and smartphones
- Tablet PCs
- Media players
- · Digital still cameras
- Portable navigation devices (GPS)

The TS3USBA225 is a double-pole, triple throw (DP3T) multiplexer that includes a low-distortion audio switch, and two USB 2.0 High-Speed (480 Mbps) switches in the same package. This configuration allows the system designer to use a common connector for audio, and USB data. The audio switch is designed to allow audio signals to swing negatively which makes this common connector configuration possible. The TS3USBA225 has a V_{CC} range of 2.7 V to 4.3 V with the capability to pass true-ground audio signals down to V_{CC} -4.3 V. The device also supports a power-down mode that can be enabled when both SEL controls are low to minimize current consumption when no signal is transmitting. The TS3USBA225 also features internal shunt resistors on the audio path to reduce clicks and pops that may be heard when the audio switches are selected.

Top View

12

6

R

SEL1

GND

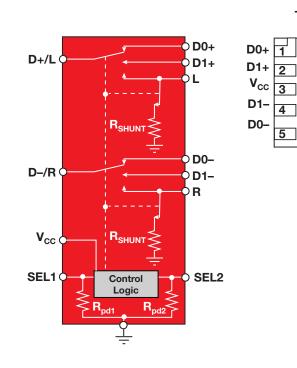
8 D-/R

7 SEL2

11

10 D+/L

9



Applications

DPDT MHL[™] (3 Gbps) and USB 2.0 High-Speed (480 Mbps) Switch with Integrated ID line Mux TS3USB3200



Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3usb3200

Key Features

- MHLTM switch
 - Supports 5 Gbps data rate
 - High bandwidth of 6 GHz
 - 2.5 pF CON typical
- High-speed USB switch:
 6 GHz Bandwidth (-3 dB)
 3.0 pF CON
- 1.8-V compatible control input (SEL1 and SEL2) threshold
- Integrated USB/MHLTM ID line switch for easy information control
- Minimized current consumption (<~30uA) during normal operation
- Flexible power control: Device can be powered by V_{BUS} without V_{CC}
- Over-Voltage Tolerance (OVT) on all I/O pins up to 5.5 V without external components
- ESD performance tested per JESD 22
 - 2000-V human body model (A114-B, Class II)
 - 1000-V charged device model (C101)
- 16-Pin RSV package
 - 2.6×1.8 mm, 0.4 mm pitch

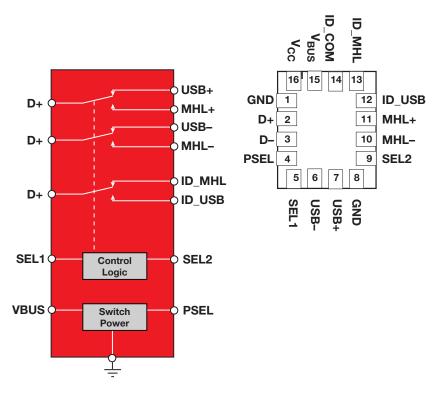
Applications

- Cell phones and smartphones
- Tablet PCs
- Portable instrumentation
- Digital still cameras

The TS3USB3200 is a Double-Pole, Double Throw (DPDT) multiplexer that includes a high-speed Mobile High-Definition Link (MHL) switch and an USB 2.0 high-speed (480Mbps) switches in the same package. Also included is a Single-Pole, Double Throw (SPDT) USB/MHL ID switch for easy information control. These configurations allow the system designer to use a common USB or Micro-USB connector for both MHL video signals and USB data.

The TS3USB3200 has a V_{CC} range of 2.7 V to 4.3 V and also has the option to be powered by V_{BUS} alone without V_{CC}. This device supports Over-Voltage Tolerance (OVT) feature, which allows the I/O pins to withstand over-voltage conditions (up to 5.5 V). The power-off protection feature forces all I/O pins to be in high-impedance mode when power is not present, allowing full isolation of the signals lines under such condition without excessive leakage current. The select pins of TS3USB3200 are compatible with 1.8 V control voltage, allowing them to be directly interfaced with the General Purpose I/O (GPIO) from a mobile processor.

The TS3USB3200 comes with a small 16-pin QFN package with only 2.6 mm x 1.8 mm in size, which makes it a perfect candidate to be used in mobile applications.



Applications

12-channel 1:2 Mux/Demux for DDR3 Applications **TS3DDR3812**

NEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/ts3ddr3812

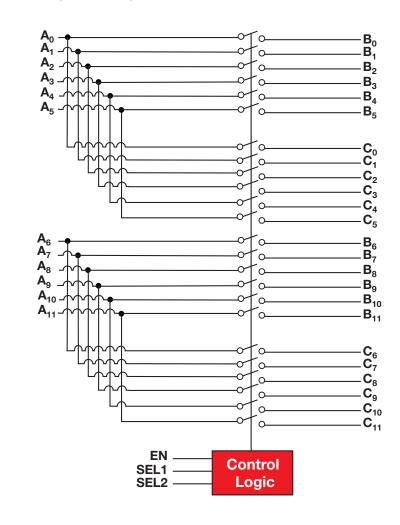
Key Features

- Compatible with DDR3 SDRAM standard (JESD79-3D)
- Wide bandwidth of over 1.9 GHz (-3 dB)
- Low propagation delay (tpd = 40 ps)
- · Low and flat ON-state resistance $(r_{ON} = 8 \Omega \text{ typ})$
- Low input/output capacitance (CON = 5.6 pF typ)
- Low crosstalk (XTALK = -43 dB typ)
- V_{CC} operating range from 3 V to 3.6 V
- Rail-to-rail switching on data I/O Ports (0 to V_{CC})
- I_{OFF} protection prevents current leakage in powered-down state
- ESD performance tested per JESD22 2-kV human body model (A114B,
 - Class II)
 - o 1-kV charged device model (C101)
- 42-pin RUA package (9 x 3.5 mm, 0.5 mm pitch)

Applications

- DDR3 signal switching
- DIMM modules
- Notebook/desktop PCs
- Servers

The TS3DDR3812 is a 12-channel, 1:2 multiplexer/demultiplexer switch designed for DDR3 applications. It operates from a 3 to 3.6 V supply and offers low and flat ON-state resistance as well as low I/O capacitance which allow it to achieve a typical bandwidth of 1.675 GHz. Channels A0 through A11 are divided into two banks of six bits and are independently controlled via two digital inputs called SEL1 and SEL2. These select inputs control the switch position of each 6-bit DDR3 source and allow them to be routed to one of two end-points. Alternatively, the switch can be used to connect a single endpoint to one of two 6-bit DDR3 sources. For switching 12-bit DDR3 sources, simply connect SEL1 and SEL2 together externally and control all 12 channels with a single GPIO input. An EN input allows the entire chip to be placed into a high-impedance (Hi-Z) state while not in use. These characteristics make the TS3DDR3812 an excellent choice for use in memory, analog/digital video, LAN, and other high-speed signal switching applications.



TS3DDR3812 block diagram.

RUA Package

(Top View)

C0 B0 C1 B1

42 41 40 39

(38 **B**2

(37

(36 В3

(35 СЗ

(34 В4

(31

(29 **B**6

28 C6

27 В7

(26 C7

(25 R8

(24 C8

23 **B**9

21 22 C9

C2

C4 (33

B5 (32

C5

vcc (30

vcc

A0

A1

A2

A3

A4

A٤

EN

SEL1

SEL2

A6

Ag 14

A11 16

vcc 17

10

11 A7

12 A8

13

15 A10

18 19 20

C11 B11 C10 B10

Applications

Dual SP2T (USB2.0 and UART) with Integrated Impedance and Charger Detection TSU6111/A



Get samples, data sheets and app reports at: www.ti.com/sc/device/PARTnumber

Key Features

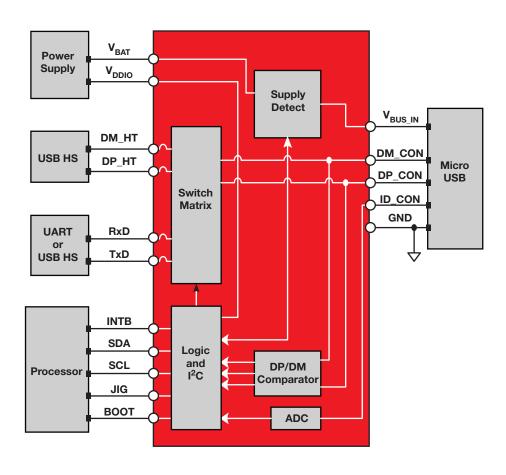
- Dual SP2T switch (both channels support USB2.0 speed) with impedance detection
- Micro-USB accessories and charger detection
 - Detection is compatible with CEA-936A (4-Wire Protocol, UART interface)
 - Plugin/unplug detection, impedance based accessory detection, charger type detection
- Low input/output capacitance C_{ON}=8pF typ.
- High bandwidth (920 MHz) and low $r_{ON}~(8~\Omega)$
- Supports DSS for tablet PC application
- Integrated ESD and surge protection
 IEC61000-4-2 ESD protection on
 VBUS, DP, DM, ID
 - ${\rm o}$ Surge protection on ${\rm V}_{\rm BUS},$ DP and DM pins
- I²C interface with host processor
- 20-WCS (2.4mm × 1.9mm) package

Applications

- Cell phones, tablet computers
- Digital cameras, camcorders
- Portable navigation devices

The TSU6111A is a high performance differential autonomous SP2T switch with impedance detection. The switch supports the detection of various accessories that are attached through DP, DM, and ID. The charger detection satisfies USB charger specification v1.1 and VBUS_IN has a 28 V tolerance to eliminate the need for external protection. Power for this device is supplied through V_{BAT} of the system or through V_{BUS} IN when attached to a charger.

The SP2T switch is controlled by the automatic detection logic or through manual configuration of the I^2 C. JIG and BOOT pins are used when a USB or UART JIG cable is used to test the device in the development and manufacturing. TSU6111A has open-drain JIG output (active low).



Applications

USB to USB-UART-Audio-Video Switch TSU6712/A

PREVIEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/PARTnumber

Key Features

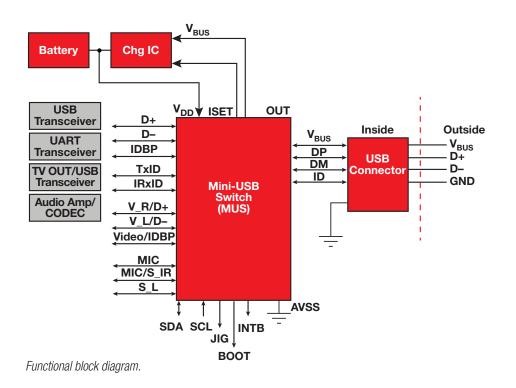
- USB to-USB,-UART,-audio, and video
- ESD performance DP/DM/ID/VBUS to GND
 - o ±8-kV contact discharge
 - ±15-kV air gap discharge
- I²C control compatibility
- Built-in impedance detection
- 25-bump WCSP (1.97 mm × 1.97 mm) Package

Applications

- High-end smartphones
- Netbook
- Tablets
- Mobile internet devices
- Portable handheld device

The TSU6712A is a multiple SP4T switch with impedance detection. The switch features impedance detection, which supports the detection of various accessories that are attached through DP and DM. The TSU6712A is fully controlled using I²C and enables USB data, stereo and mono audio, video, microphone, and UART data to use a common connector port.

Power for this device is supplied through V_{BAT} of the system or through V_{BUS} when attached. The switch can be controlled through I^2C . JIG and BOOT pins are used when a USB, UART JIG cable is used to test during development and manufacturing.



Applications

USB, Audio, and Charger detection

TSU5611

Get samples, data sheets and app reports at: www.ti.com/sc/device/tsu5611

Key Features

- Dual SP3T & SPST analog switch with impedance detection.
- New interface IC for various signaling in mobile phones
 - Audio switch
- Two USB 2.0 high-speed switch
- Smart detection
 - Plug-in/un-plug detection
 - USB charger detection
 - Proprietary accessory detection with impedance sensing
- Additional protection
 - IEC61004 level 4 ESD protection
 4pins (VBUS, DP,DM, ID)
- I²C interface with host processor
- Low input/output capacitance CON=8pF typ.
- Supports DSS for tablet PC application
- 20-WCS(2.4mm × 1.9mm) package

Applications

- Cell phone, netbook, MID
- Portable handheld device

The TSU5611 is designed to interface the cellular phone UART, USB, and audio chips with external peripherals via a micro-USB connector. The switch features impedance detection for identification of various accessories that are attached through DP and DM of the micro-USB port. When an accessory is plugged into the micro-USB port, the switch uses a detection mechanism to identify the accessory (see the State Machine for details). It will then switch to the appropriate channel—data, audio, or UART.

The TSU5611 has an I^2C interface for communication with the cellular phone baseband or applications processor. An interrupt is generated when anything plugged into the micro-USB is detected. Another interrupt is generated when the device is unplugged.

VSupply

Supply

Detect

V_{BUS}

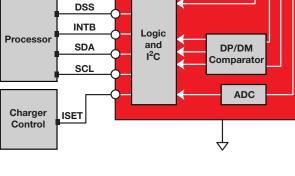
DM

DP

ID

Micro

USB



Switch

Matrix

Audio Amp

Neg. Rail and

Click/Pop

Free

Functional block diagram.

USB_DM

USB_DP

UART RX

UART TX

AUDIO_L

AUDIO_R

MIC

USB

UART

AUDIO1



Applications

Single-Cell Charger and SP2T Switch TSU8111

PREVIEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/tsu8111

Key Features

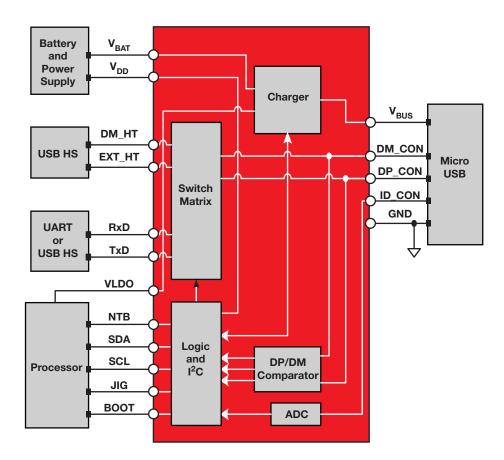
- Fully compliant USB singlecell charger
 - Input voltage dynamic power management
 - 50 mA integrated low dropout regulator (LDO)
 - 1% charge voltage regulation accuracy
 - o 8% charge current accuracy
 - Programmable charging current limit up to 950 mA for wall adapters
- Dual SP2T
 - USB & UART support 2.0 high speed
 - Impedance detection
- Charger detection
 - USB BCDv1.1
 - o V_{BUS} & data contact detection
 - Primary & secondary detection
- Additional features
 - I²C interface with host processor
 Support control signals used in
 - manufacturing (JIG, BOOT)
 Interrupt for attach & detach accessory
- Compatible accessories
 - USB cable
 - UART cable
 - USB charger BCDv1.1
- Additional protection
 o 28 V V_{BUS} rating with OVP
 - Thermal regulation & shutdown
- ESD per JESD 22
 2000V HBM (A114-B Class II)
 1000V CDM (C101)
- ESD performance VBUS/DP/DM/ID to GND
 - ±8 kV contact discharge (IEC 61000-4-2)
 - (IEC 01000-4-2
- Package
 o 20-WCSP (2.0 mmx1.6 mm)

Applications

- Cell phones & smart phones
- Tablet PCs
- Digital cameras & camcorders
- GPS navigation systems
- MicroUSB interface with USB/UART

The TSU8111 is a differential high-performance automated SP2T switch with impedance detection and integrated Li-Ion linear charger device targeted at space-limited portable applications. The switch features impedance detection which supports the detection of various accessories that are attached through DP, DM and ID. The charger detection satisfies USB charger specification v1.1. V_{BUS} has 28 V tolerance to avoid external protection. The device operates from either a USB port or dedicated charger and supports charge currents up to 950 mA. Power for this device is supplied through V_{BAT} of the system or through V_{BUS} when attached.

The switch is controlled by automatic detection logic or through I²C manually. JIG and BOOT pins are used when a USB, UART JIG cable is used to test in the development and manufacturing. TSU8111 has open-drain JIG output (active low) and TSU8112 has push-pull JIG output (active high).



Functional block diagram.

Applications

Charger-Detection Device BQ24392

NEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/BQ24392

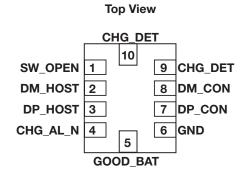
Key Features

- Charger-detection device
 - USB BCv1.2 compliant
 - V_{BUS} detection
 - Data contact detection
 - Primary & secondary detection
 - Dead battery provision. 32 min timer
- Switch
 - USB 2.0 high speed
- Compatible accessories
 - Dedicated charging port
 - Standard charging port
 - Charging port
- Other chargers detected
 - Apple charger
 - Tom Tom charger
 - Non-compliant USB charger
- Max voltage
- 30V tolerance on V_{BUS}
- ESD on V_{BUS} , DP, DM to GND
 - ± 8-KV contact discharge (IEC 61000-4-2)
- Package
 o 10-pin uQFN RSE

Applications

- Smart-phones
- Cell phone
- Tablets
- GPS systems

The BQ24392 is a charger-detection device with an integrated isolation switch for use with a micro/mini USB port. The device is compliant with USB battery charging specification v1.2. This device allows cell phones & tablets to be charged from different adapters including USB BCv1.2 compliant and non-standard USB chargers. These non-standard chargers include Apple, TomTom & non-compliant USB chargers. The BQ24392 conforms to Dead Battery Provision (DBP) specified in BCv1.2. This includes a 32-min timer that cannot exceed 45 mins. This device has a USB 2.0 switch that supports high speed. In addition to USB connector and host pins, BQ24392 has one input and three output pins, resulting in minimum software workload for the system to interact with the device. V_{BUS} has 28 V tolerance to avoid external protection. Power for this device is supplied via V_{BUS} when accessory is attached.



Applications

USB, UART, AUDIO, ID, MIC, & Load Switch TSU6721

PREVIEW

Get samples, data sheets and app reports at: www.ti.com/sc/device/tsu6721

Key Features

- Switch matrix
 - USB & UART switch support USB 2.0 HS
 - Audio switch with negative signal capability
 - ID bypass switch
 - V_{BUS} to MIC switch
 - DP to MIC switch to support MCPC
- Load switch
 - o 100 m Ω load switch
 - OTG support
 - o 28V V_{BUS} rating with overvoltage protection
 - Programmable overcurrent limiter/ protection
- Charger detection
 OUSB BCDv1.2 compliant
 V_{BUS} detection
 - Data contact detection
 - o Primary & secondary detection Compatible accessories
- USB chargers (DCP, CDP)
 o Apple charger
 o USB data port
 - Audio headset with MIC & remote
 - Docking support
 - Factory cable
- Surge Protection on V_{BUS}/DP/DM
 USB connector pins without external component
 - o I²C interface with host processor
 - Switches controlled by automatic detection or manual control
 - Interrupts generated for plug/unplug
 - ${\rm o}$ Decoupling FET switch to ${\rm V}_{\rm BUS}$ added to reduce degradation on MIC line
 - Support control signals used In manufacturing (JIG, BOOT)

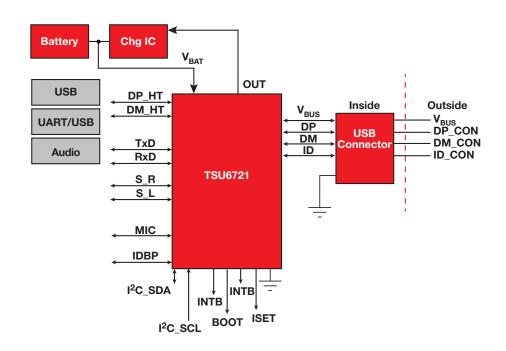
Applications

- Cell phones & smart phones
- Tablet PCs
- Digital cameras & camcorders
- GPS navigation systems
- Micro USB interface with USB/UART/ AUDIO

TSU6721 is a high-performance USB port multimedia switch featuring automatic switching and accessory detection. The device connects a common USB port to pass audio, USB data, charging, On The Go (OTG) and factory mode signals. The audio path has negative signal capability includes left (mono/stereo), right (stereo) as well as micro-phone signals. Furthermore, TSU6721 is compatible with the MCPC specification.

TSU6721 features impedance detection which supports the detection of various accessories that are attached through DP, DM and ID pins of the USB connector. The switch is controlled by automatic switching or manually through l^2C .

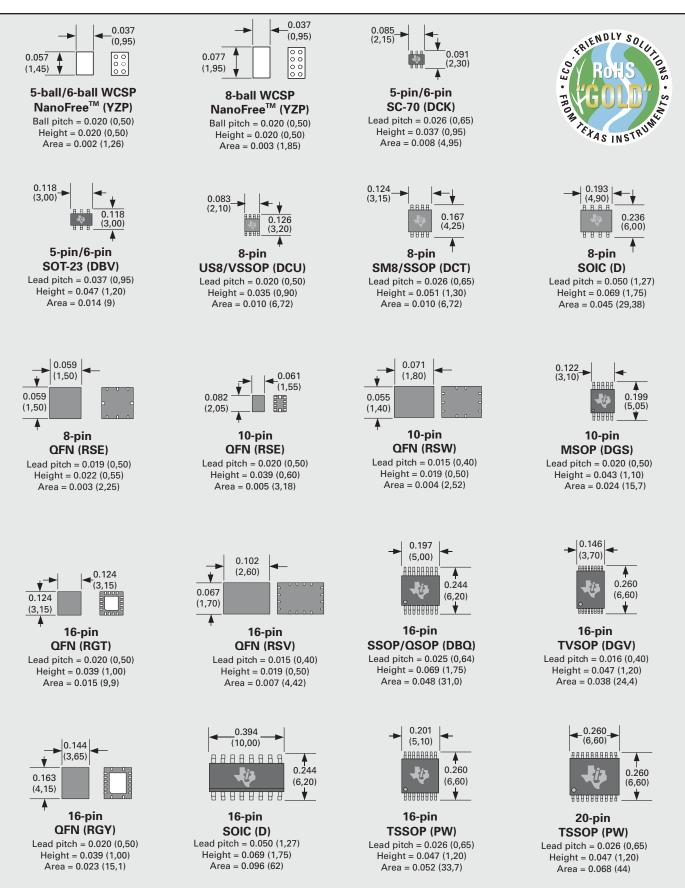
TSU6721 has an integrated, low-resistive, Load Switch that is used to isolate the charger from the external connector. Overvoltage protection and programmable overcurrent limiter/protection are additional features included to the load switch. The charger detection satisfies USB charger specification v1.2. In addition to DCP, CDP & SDP, the device also detects Apple Chargers. Power for this device is supplied through V_{BAT} of the system or through V_{BUS} when attached. TSU6721 supports factory mode testing when a USB/UART JIG cable is used in development and manufacturing.



Functional block diagram.

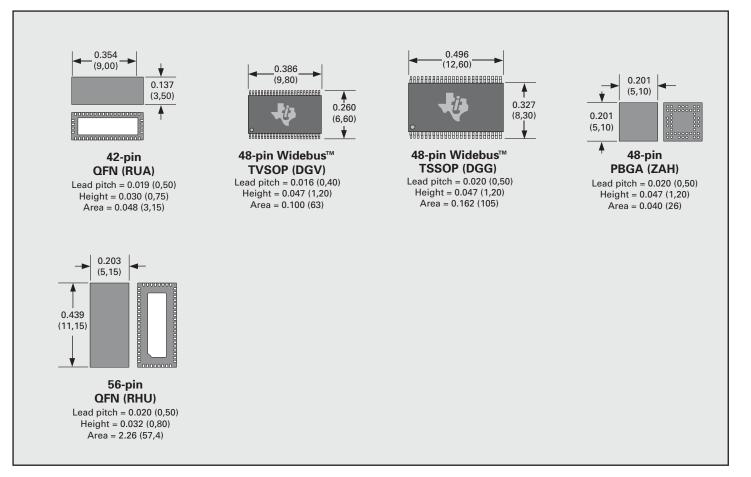
Resources





Resources

Packages



Sample and Quality Information

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Korea		080-551-2804		
Malaysia		1-800-80-3973		
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